

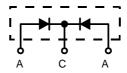
Common Cathode Fast Recovery Epitaxial Diode (FRED)

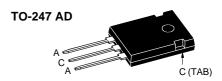
DSEK 60 I_{EAVM}

 $I_{FAVM} = 2x 30 A$ $V_{RRM} = 600 V$

 $t_{rr} = 35 \text{ ns}$

V _{RSM}	V _{RRM}	Туре
V	V	
640	600	DSEK 60-06A





A = Anode, C = Cathode, TAB = Cathode

Symbol Test Conditions		Maximum Ratings	
FRMS (1) FAVM (1) FRM	$T_{VJ} = T_{VJM}$ $T_{C} = 85^{\circ}C$; rectangular, d = 0.5 $t_{p} < 10 \ \mu s$; rep. rating, pulse width limited by T_{VJM}	50 30 375	A A A
I _{FSM}	$T_{VJ} = 45$ °C; $t = 10$ ms (50 Hz), sine $t = 8.3$ ms (60 Hz), sine	300 320	A A
	$T_{VJ} = 150$ °C; $t = 10$ ms (50 Hz), sine $t = 8.3$ ms (60 Hz), sine	260 280	A A
l²t	$T_{VJ} = 45$ °C $t = 10$ ms (50 Hz), sine $t = 8.3$ ms (60 Hz), sine	450 420	A ² s A ² s
	$T_{VJ} = 150$ °C; $t = 10$ ms (50 Hz), sine $t = 8.3$ ms (60 Hz), sine	340 320	A ² s A ² s
T _{VJ} T _{VJM} T _{stg}		-40+150 150 -40+150	°C °C °C
P _{tot}	T _C = 25°C	125	W
M _d	Mounting torque	0.81.2	Nm
Weight		6	g

Symbol	Test Conditions	Characteristic Values		
		typ.	max.	
I _R	$\begin{array}{lll} T_{_{VJ}} = 25^{\circ}C & V_{_{R}} = V_{_{RRM}} \\ T_{_{VJ}} = 25^{\circ}C & V_{_{R}} = 0.8 \bullet V_{_{RRM}} \\ T_{_{VJ}} = 125^{\circ}C & V_{_{R}} = 0.8 \bullet V_{_{RRM}} \end{array}$		100 50 7	μΑ μΑ mA
V _F	$I_F = 37 \text{ A};$ $T_{VJ} = 150^{\circ}\text{C}$ $T_{VJ} = 25^{\circ}\text{C}$		1.4 1.6	V V
$\mathbf{V}_{_{TO}}$ $\mathbf{r}_{_{T}}$	For power-loss calculations only $\rm T_{VJ} = \rm T_{VJM}$		1.01 7.1	$\begin{matrix} V \\ m\Omega \end{matrix}$
R _{thJC} R _{thCK} R _{thJA}		0.25	1 70	K/W K/W K/W
t _{rr}	$I_F = 1 \text{ A}; -\text{di/dt} = 100 \text{ A/}\mu\text{s}; V_R = 30 \text{ V}; T_{VJ} = 25^{\circ}\text{C}$	35	50	ns
I _{RM}	$V_R = 350 \text{ V}; I_F = 30 \text{ A}; -di_F/dt = 240 \text{ A}/\mu\text{s}$ $L \le 0.05 \mu\text{H}; T_{VJ} = 100^{\circ}\text{C}$	10	11	А

Features

- International standard package JEDEC TO-247 AD
- Planar passivated chips
- · Very short recovery time
- · Extremely low switching losses
- Low I_{RM}-values
- Soft recovery behavior
- Epoxy meets UL 94V-0

Applications

- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Advantages

- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- · Low noise switching
- · Low losses
- Operating at lower temperature or space saving by reduced cooling

 $[\]odot$ I_{FAVM} rating includes reverse blocking losses at T_{V,M}, V_R = 0.8 V_{RRM}, duty cycle d = 0.5 Data according to IEC 60747 and refer to a single diode unless otherwise stated. IXYS reserves the right to change limits, test conditions and dimensions



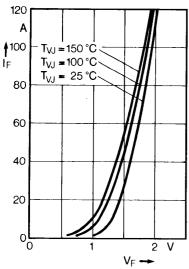
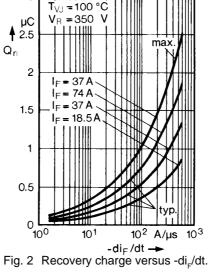


Fig. 1 Forward current versus voltage drop.



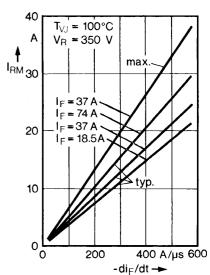


Fig. 3 Peak reverse current versus -di_F/dt.

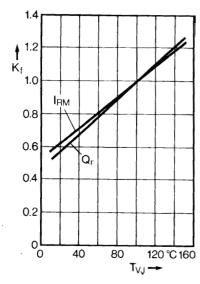


Fig. 4 Dynamic parameters versus junction temperature.

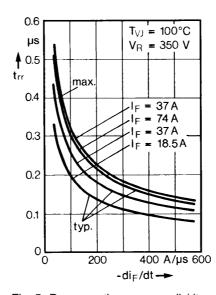


Fig. 5 Recovery time versus -di_F/dt.

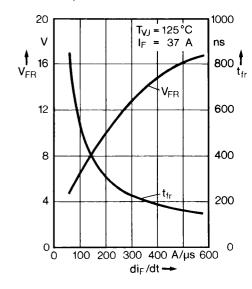


Fig. 6 Peak forward voltage versus di_F/dt.

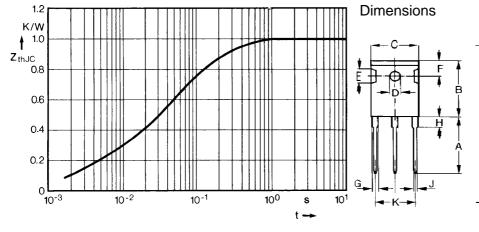


Fig. 7 Transient thermal impedance junction to case.

		Dim.	Millimeter		Inches	
			Min.	Max.	Min.	Max.
-	L 	A B	19.81 20.80	20.32 21.46	0.780 0.819	0.800 0.845
Ī	<u>VİY</u>	C D	15.75 3.55	16.26 3.65	0.610 0.140	0.640 0.144
		E F	4.32 5.4	5.49 6.2	0.170 0.212	0.216 0.244
	1	G H	1.65 -	2.13 4.5	0.065	0.084 0.177
		J K	1.0 10.8	1.4 11.0	0.040 0.426	0.055 0.433
7	M	L M	4.7 0.4	5.3 0.8	0.185 0.016	0.209 0.031
-	I N	N	2.2	2.54	0.087	0.102